

Device Modeling Report

COMPONENTS:

DIODE/ SCHOTTKY RECTIFIER/ PROFESSIONAL

PART NUMBER: HRW0702A

MANUFACTURER: HITACHI

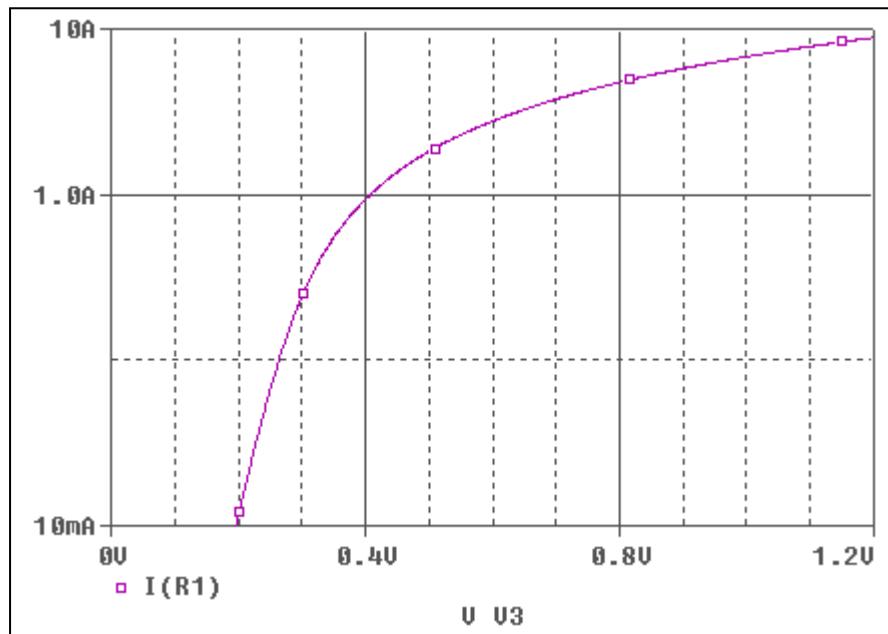


Bee Technologies Inc.

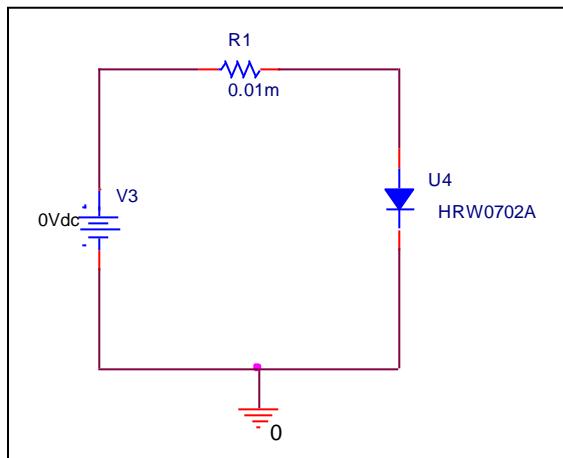
PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time
EG	Energy-band Gap

Forward Current Characteristic

Circuit Simulation Result

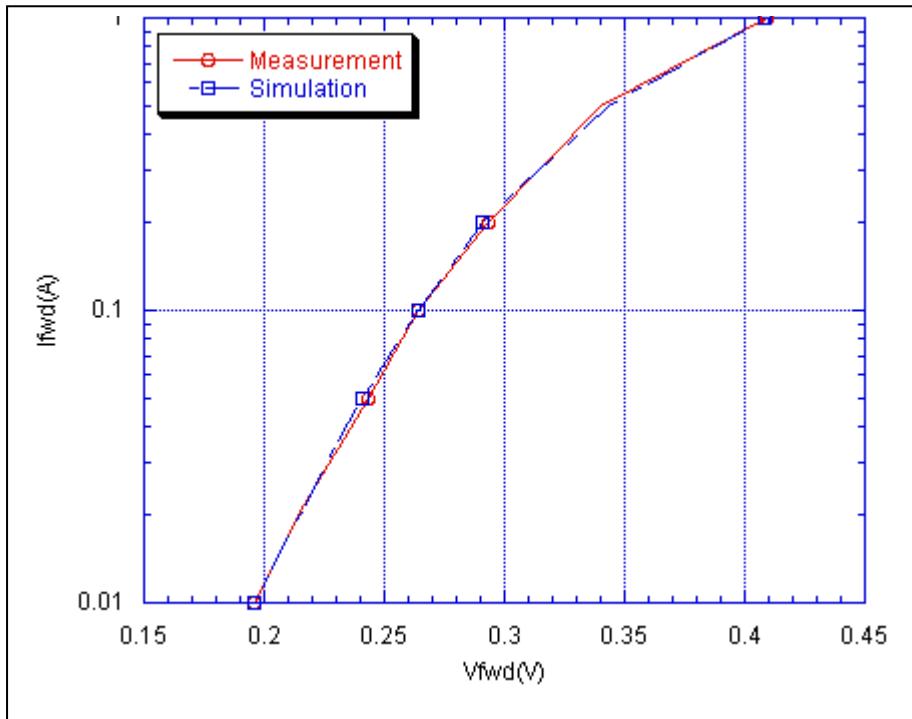


Evaluation Circuit



Comparison Graph

Circuit Simulation Result

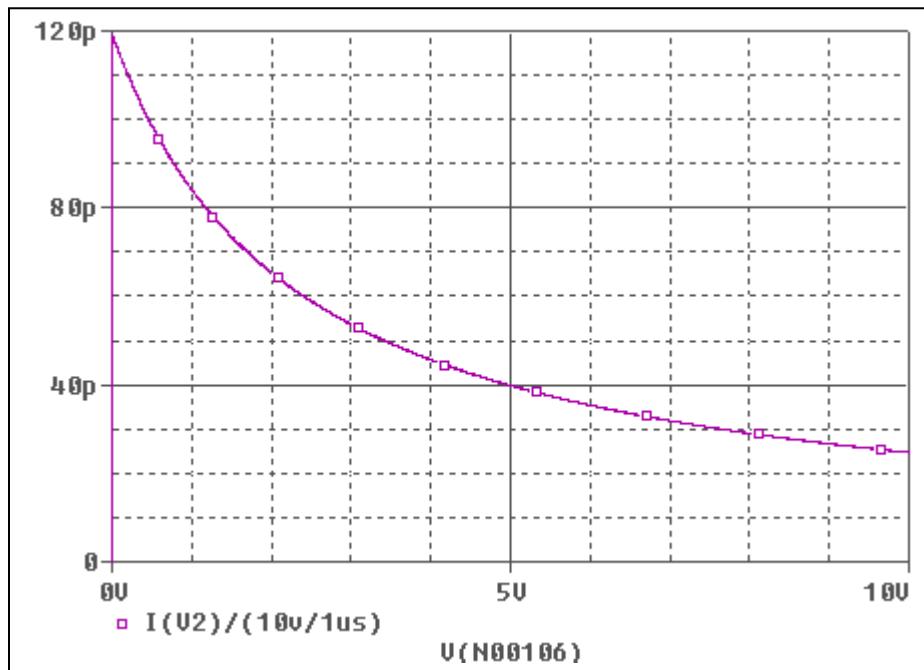


Simulation Result

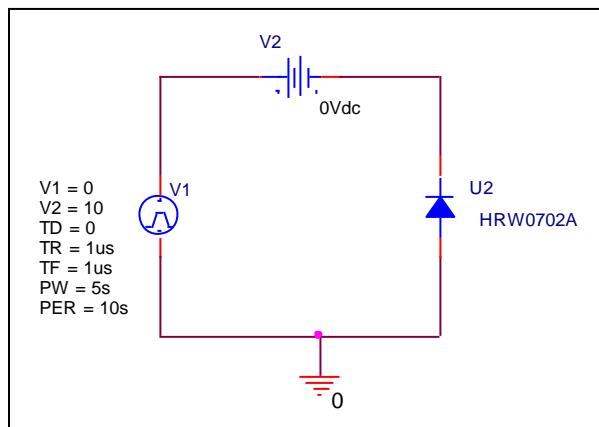
$I_{fwd}(A)$	$V_{fwd}(V)$ Measurement	$V_{fwd}(V)$ Simulation	%Error
0.01	0.196	0.195	-0.513
0.02	0.214	0.215	0.465
0.05	0.243	0.241	-0.830
0.1	0.264	0.263	-0.380
0.2	0.293	0.291	-0.687
0.5	0.340	0.343	0.875
1	0.409	0.408	-0.245

Junction Capacitance Characteristic

Circuit Simulation Result

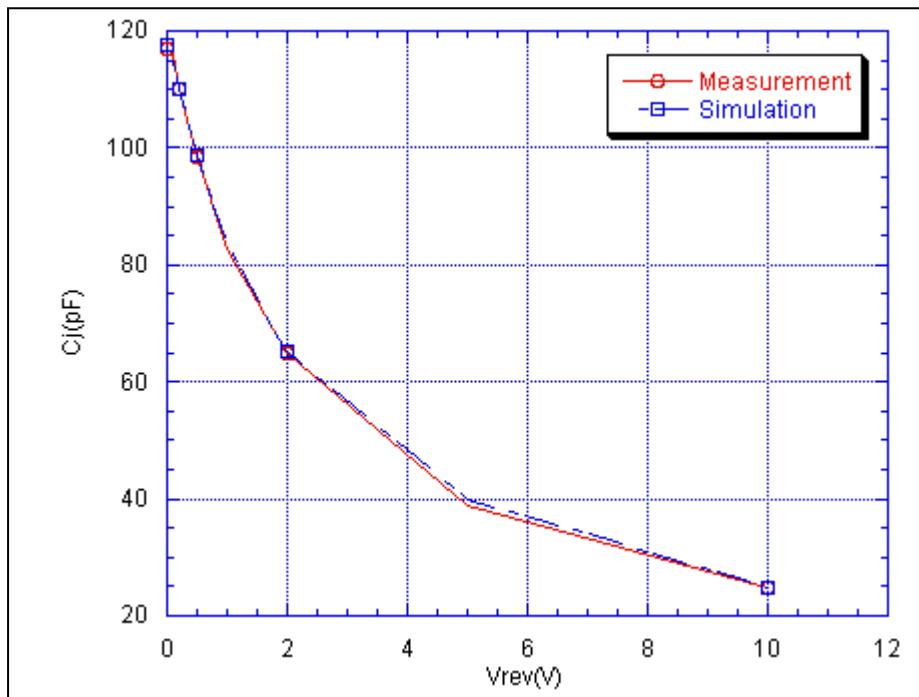


Evaluation Circuit



Comparison Graph

Circuit Simulation Result

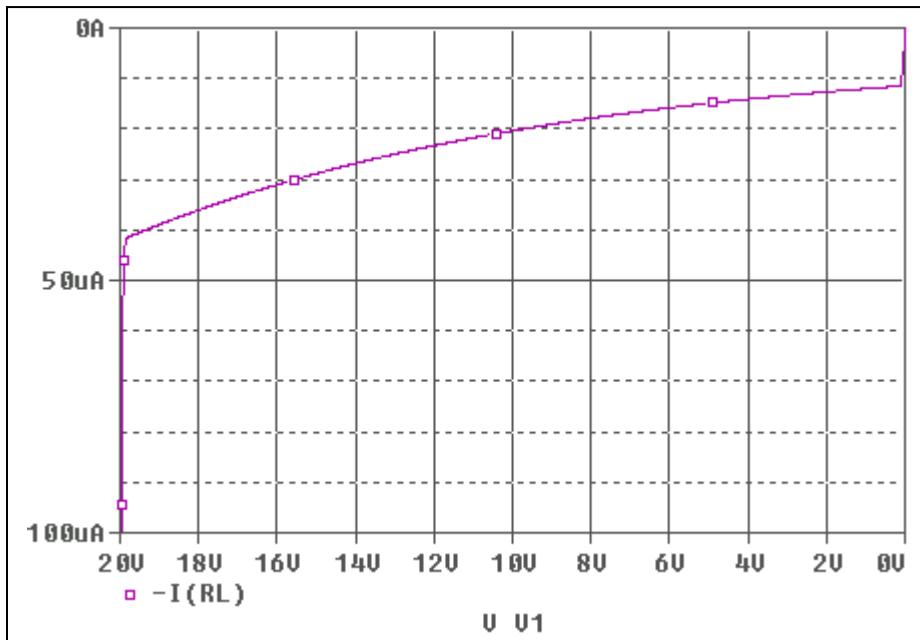


Simulation Result

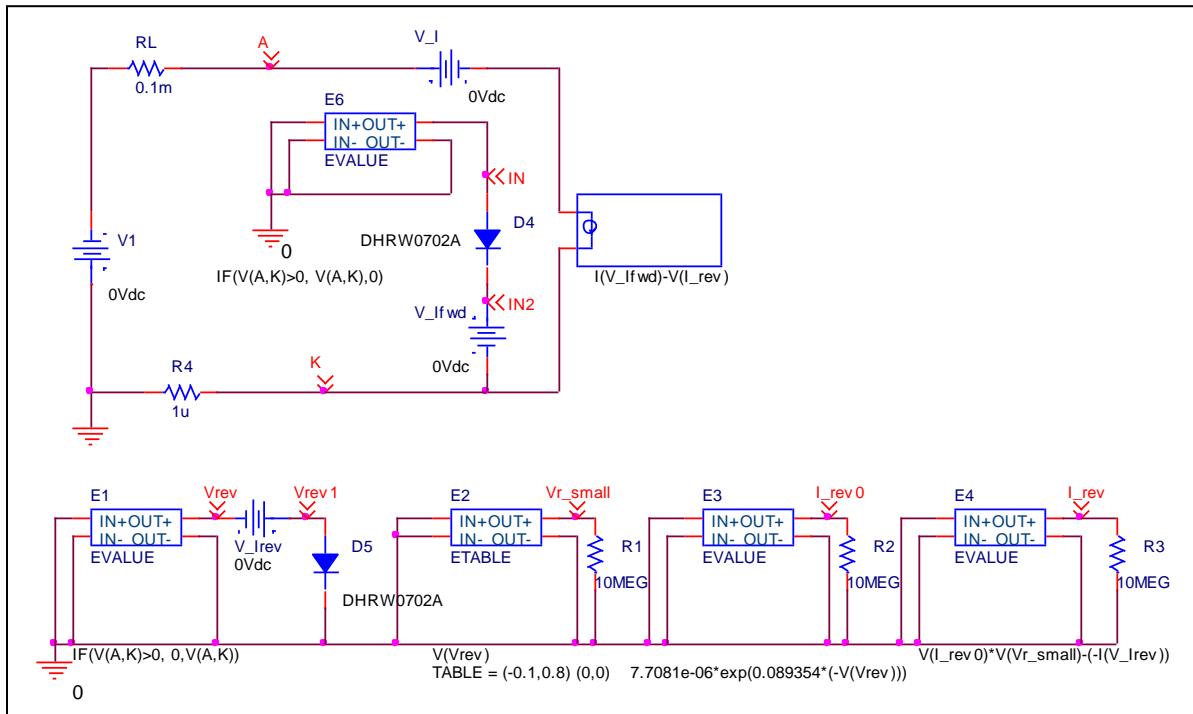
V_{rev} (V)	C_j (pF) Measurement	C_j (pF) Simulation	%Error
0	116.795	118.621	1.539
0.1	115.964	115.204	-0.660
0.2	110.035	110.621	0.530
0.5	98.461	99.277	0.822
1	82.650	84.692	2.411
2	64.941	66.063	1.698
5	38.807	40.838	4.973
10	24.723	26.188	5.594

Reverse Characteristic

Circuit Simulation Result

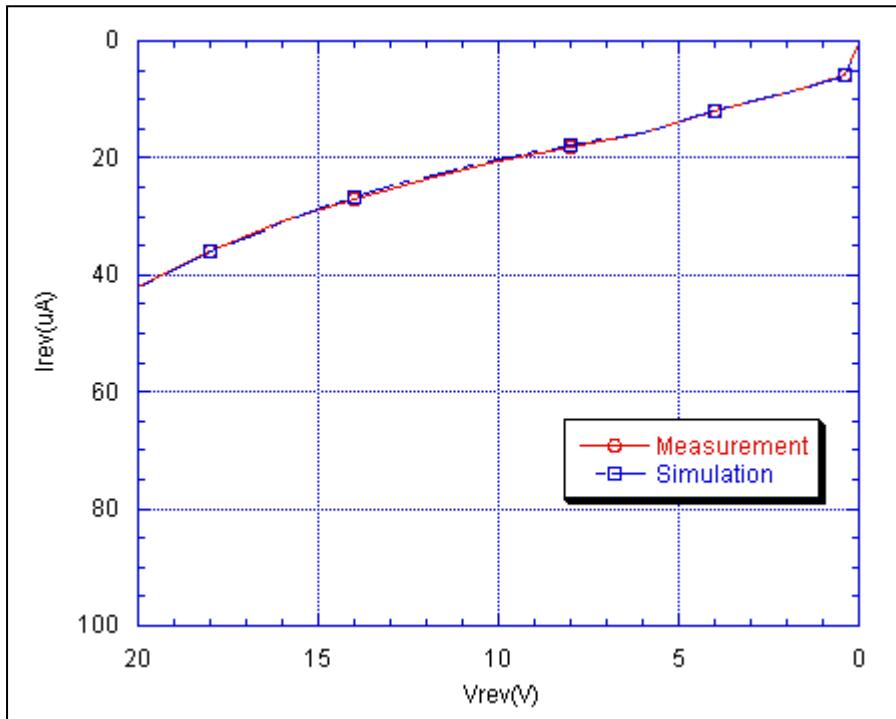


Evaluation Circuit



Comparison Graph

Circuit Simulation Result



Simulation Result

V _{rev} (V)	I _{rev} (uA) Measurement	I _{rev} (uA) Simulation	%Error
6	15.600	15.820	1.391
8	18.000	17.880	-0.671
10	20.500	20.350	-0.737
12	23.500	23.290	-0.902
14	27.000	26.820	-0.671
16	31.000	31.030	0.097
18	36.000	36.110	0.305

Reverse Characteristic

Reference

